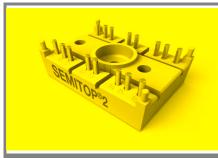
# SK 95 D



SEMITOP® 2

### **Bridge Rectifier**

#### SK 95 D

Preliminary Data

#### **Features**

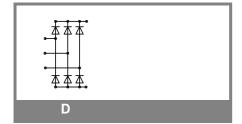
- Compact design
- · One screw mounting
- Heat transfer and insulation through direct copper bonded aluminium oxide ceramic (DCB
- Up to 1600V reverse voltage
- High surge currents
- Glass passived diodes chips
- UL recognized, file no. E 63 532

### **Typical Applications**

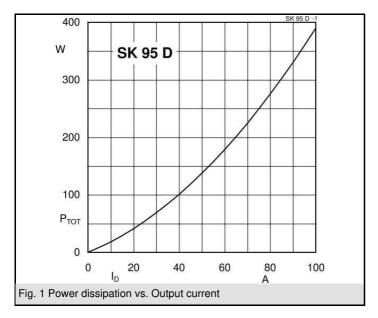
- Input rectifier for power supplies
- Rectifier

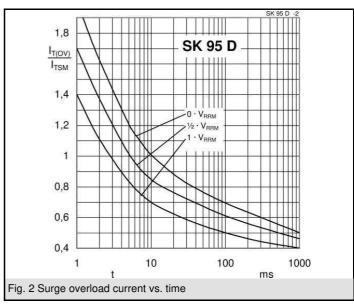
V <sub>RSM</sub>	V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>D</sub> = 95 A (full conduction)
800	800	(T <sub>s</sub> = 80 °C) SK 95 D 08
1200	1200	SK 95 D 12
1600	1600	SK 95 D 16

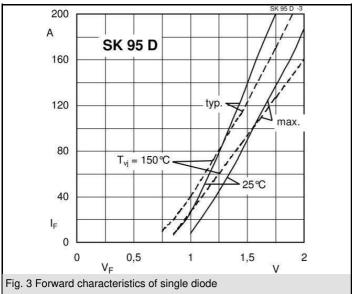
Symbol	Conditions	Values	Units
$I_D$	T <sub>s</sub> = 80 °C	95	Α
I <sub>FSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	700	Α
	T <sub>vi</sub> = 150 °C; 10 ms	560	Α
i²t	T <sub>vi</sub> = 25 °C; 8,310 ms	2450	A²s
	T <sub>vj</sub> = 150 °C; 8,310 ms	1370	A²s
V <sub>F</sub>	T <sub>vi</sub> = 25 °C; I <sub>F</sub> = 35 A	max. 1,2	V
V <sub>(TO)</sub>	T <sub>vi</sub> = 150 °C	max. 0,8	V
r <sub>T</sub>	T <sub>vi</sub> = 150 °C	max. 11	mΩ
$I_{RD}$	$T_{vj}^{3}$ = 150 °C; $V_{DD} = V_{DRM}$ ; $V_{RD} = V_{RRM}$	max. 4	mA
			mA
R <sub>th(j-s)</sub>	per diode	1,2	K/W
3 37	per module	0,2	K/W
T <sub>solder</sub>	terminals, 10s	260	°C
T <sub>vi</sub>		-40+150	°C
T <sub>stg</sub>		-40+125	°C
V <sub>isol</sub>	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3000 ( 2500 )	V
M <sub>s</sub>	mounting torque to heatsink	2	Nm
$M_t$			
m	approx. weight	19	g
Case	SEMITOP® 2	T 7	

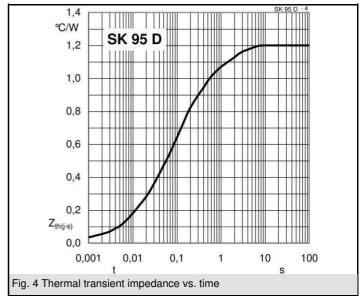


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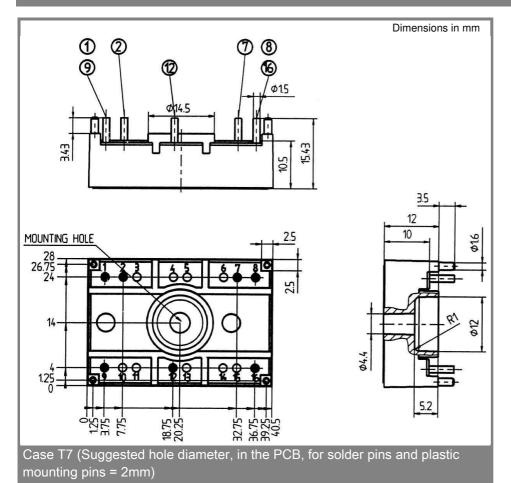


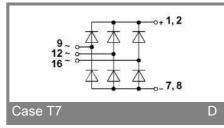






# SK 95 D





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